

Highlights of *Fundamentals of Microelectronics*

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1 Introduction to Microelectronics

Voltage Gain

Voltage gain A_v in a voltage amplifier:

$$A_v = \frac{v_o}{v_i} \quad (1)$$

Expressed in decibels (dB):

$$A_v|_{\text{dB}} = 20 \log_{10} A_v \quad (2)$$

Kirchoff's Laws

The Kirchoff Current Law (KCL).

The Kirchoff Voltage Law (KVL).

Thevenin and Norton Equivalents

Thevenin's theorem. A linear one-port network can be replaced with an equivalent circuit consisting of a voltage source v_{Thev} in series with an impedance Z_{Thev} . The equivalent voltage v_{Thev} can be calculated by $v_{\text{Thev}} = v_{\text{oc}}$; The equivalent impedance Z_{Thev} can be determined by $Z_{\text{Thev}} = \frac{v_{\text{oc}}}{i_{\text{sc}}}$.

Norton's theorem. A linear one-port network can be replaced with an equivalent circuit consisting of a current source i_{Nor} in parallel with an impedance Z_{Nor} . The equivalent current i_{Nor} can be obtained by $i_{\text{Nor}} = i_{\text{sc}}$; The equivalent impedance Z_{Nor} can be determined by $Z_{\text{Nor}} = \frac{v_{\text{oc}}}{i_{\text{sc}}}$.

Note that $Z_{\text{Thev}} = Z_{\text{Nor}}$.

2 Basic Physics of Semiconductors

Bandgap Energy

The *bandgap energy* E_g is
 $E_g =$. This is a fundamental property of the material, e.g., for silicon
 (1 eV = 1.6×10^{-19} J)

Electron Density (Charge Carrier Density)

The *density of electrons* n_i , i.e., the number of electrons per unit volume is

$$n_i = \quad . \quad (5)$$

where $k = 1.39 \times 10^{-23}$ J/K is the Boltzmann constant.